

LECTURE 18 - LED's

①

ANNOUNCEMENTS → NO LECTURE ON
THURSDAY (MIT) /
FRIDAY (NUS)

→ NO RECITATION NEXT
WEEK MON (MIT) / TUE (NUS)

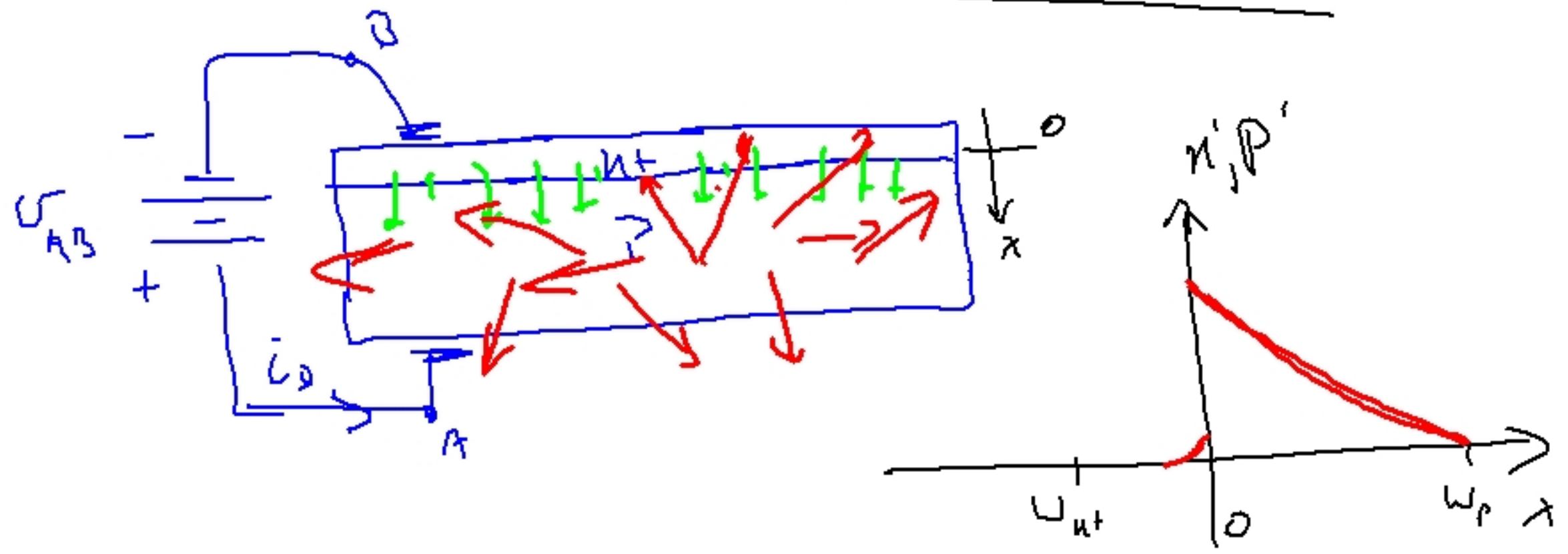
→ LECTURE 19 - LASER DIODES
WILL BE TUES 4/22 (MIT)
WED 4/23 (NUS)

In HIGH LEVEL INJECTION SITUATIONS: *

$$\tau_{rad} \rightarrow \frac{1}{B(p_0 + p')}$$

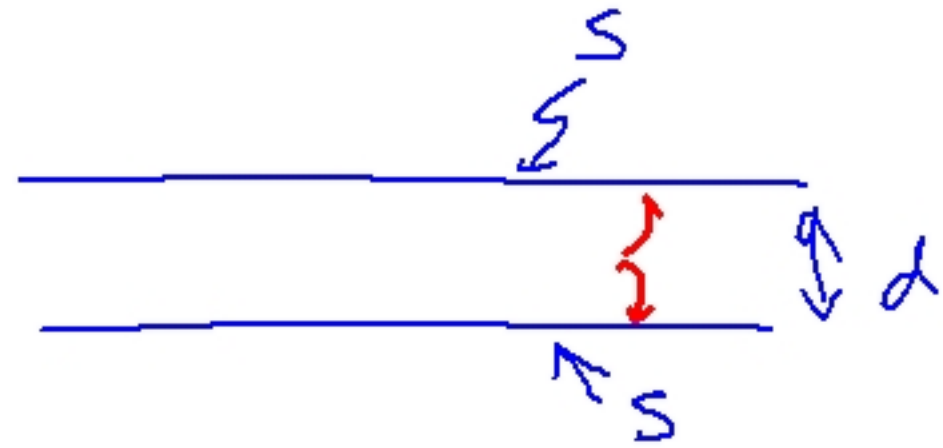
$$\tau_{rad} \downarrow \text{ as } p' \uparrow$$

$$* HLI \Rightarrow p' \approx p_0$$



3

WITH SURFACE RECOMBINATION

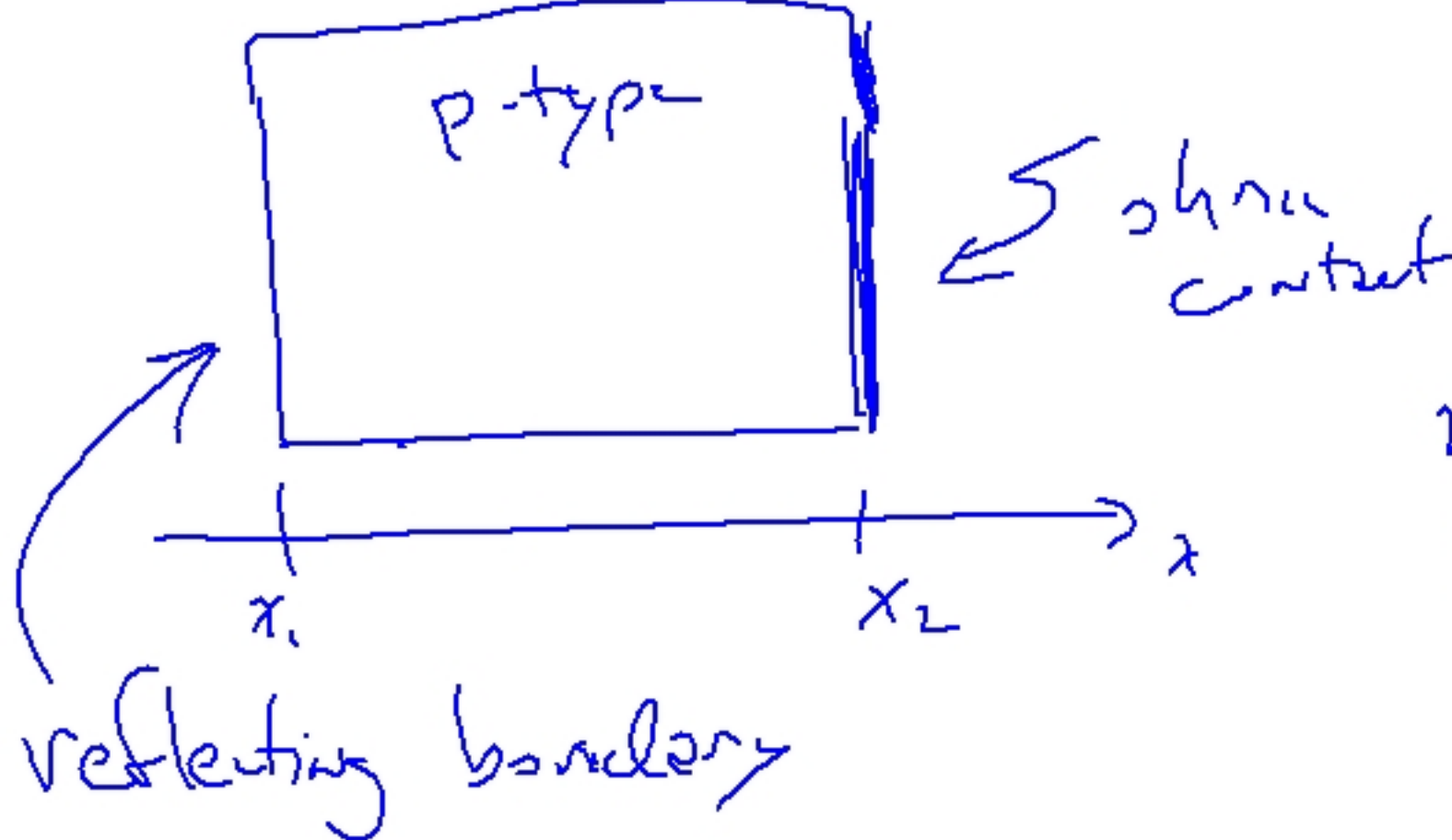


$$\frac{1}{\tilde{\kappa}_{\text{eff}}} = \frac{1}{\tilde{\kappa}_{\text{vol}}} + \frac{1}{\tilde{\kappa}_{\text{surf}}} + \frac{2s}{d}$$

$\frac{1}{\tilde{\kappa}_{\text{surf}}}$

$$\tilde{\kappa}_{\text{surf,eff}} < \tilde{\kappa}_{\text{surf}}$$

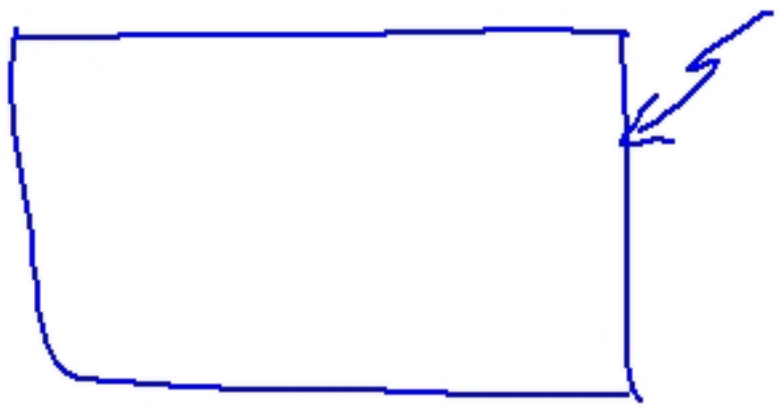
④



$$n'(x_2) = 0$$
$$p'(x_2) = 0$$

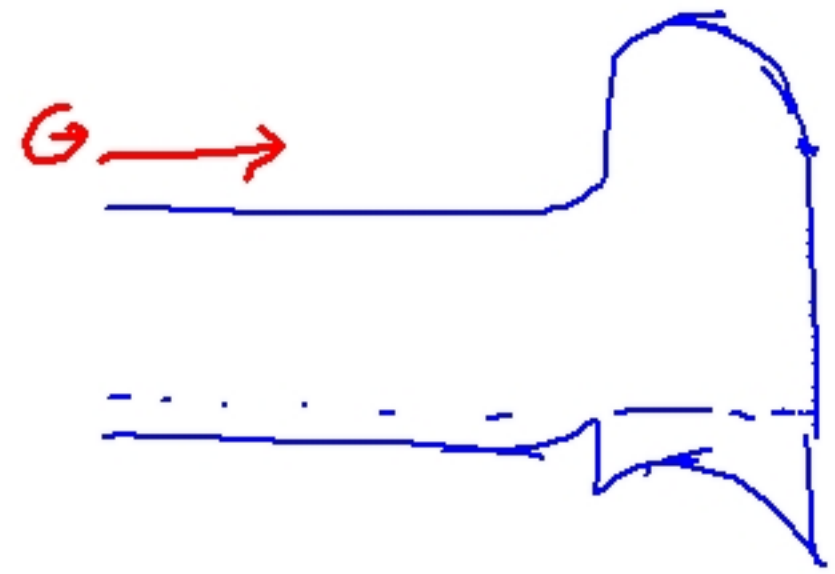
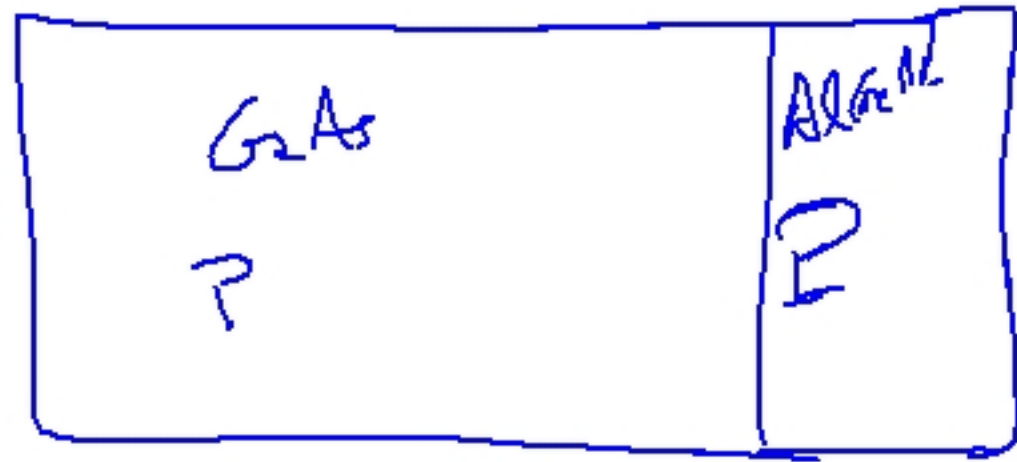
$$\left. \frac{dn'}{dx} \right|_{x_1} = 0$$

$$-D_e \frac{dn'}{dx} = s n'$$



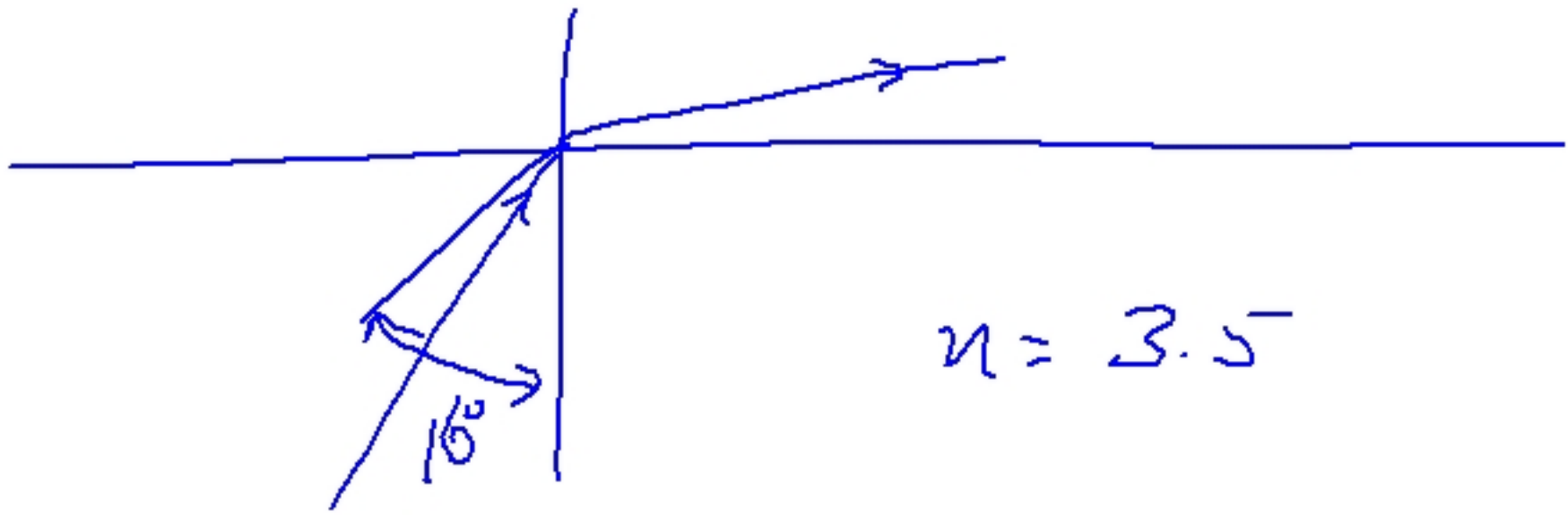
5

Use HV to shield carriers from surface

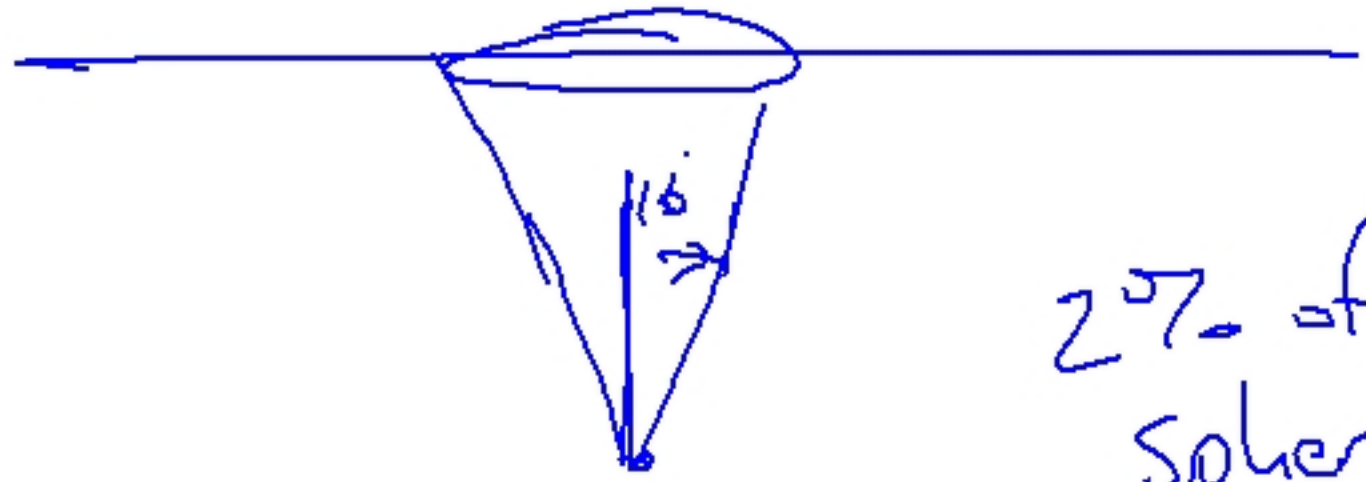


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$$n = 1.0$$



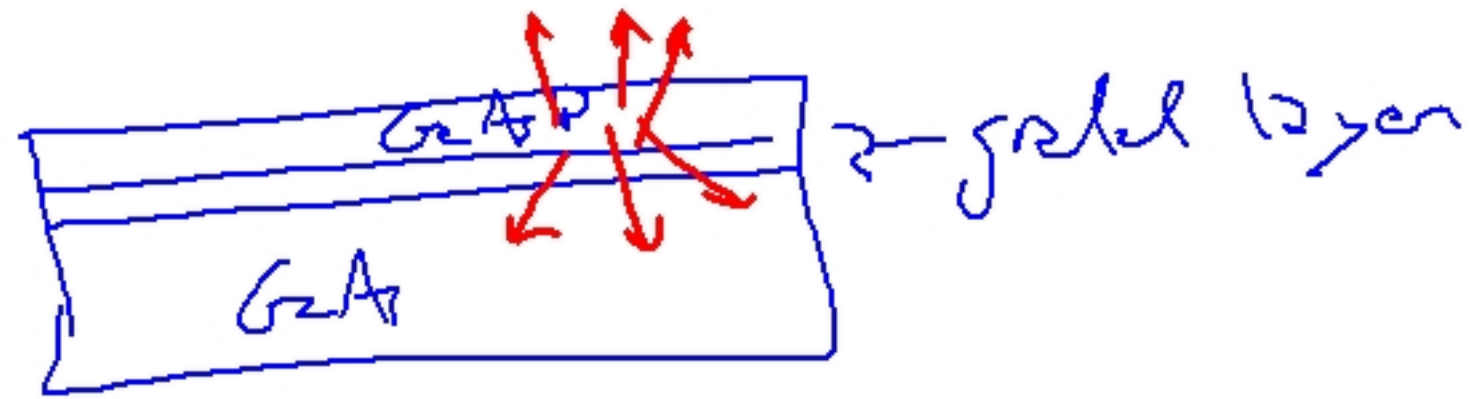
$$n = 3.5$$



20% of total
Sphere

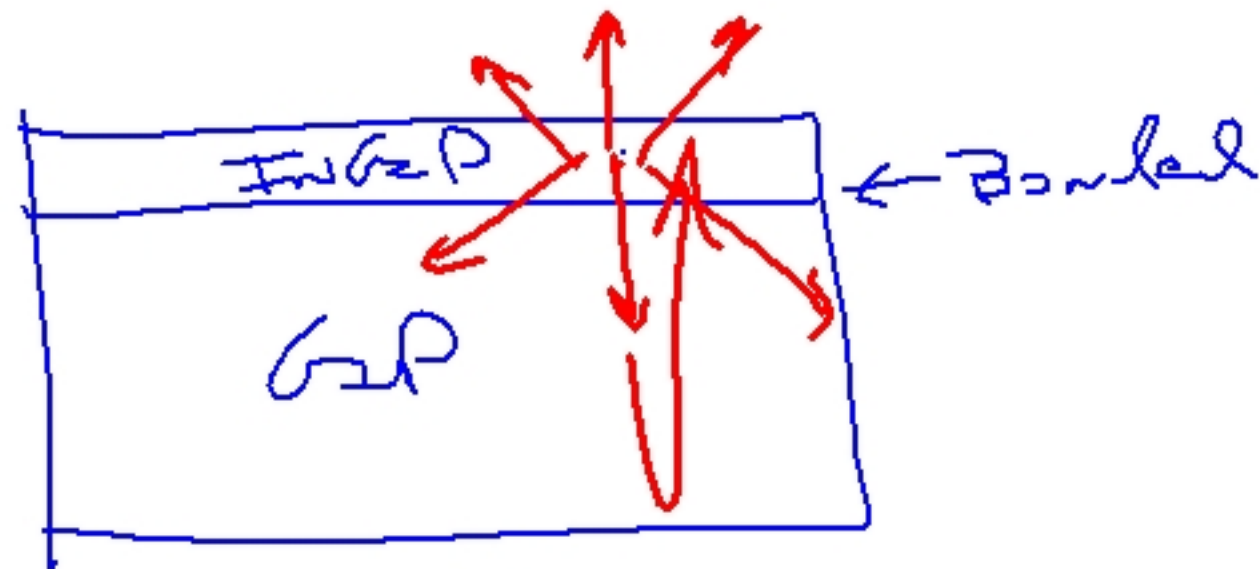
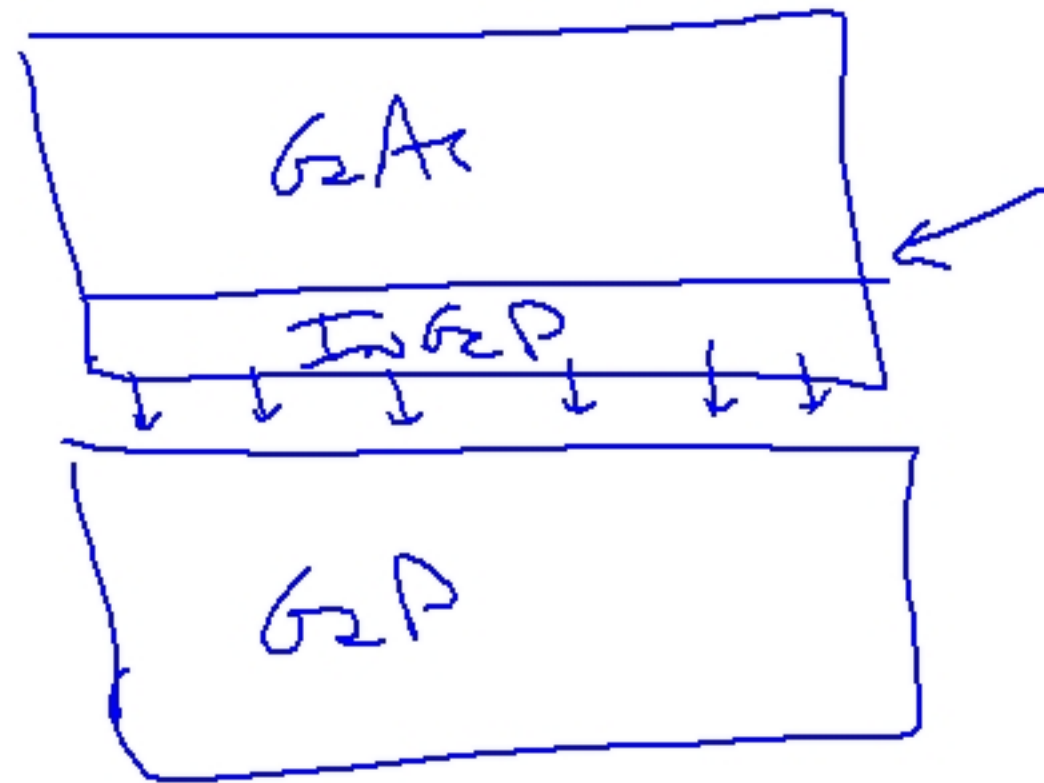
Early LED

red: $\text{GaAs}_{0.6}\text{P}_{0.4} / \text{GaAs}$



Newer red: $\text{InGaAsP} / \text{GaAs}$ lattice matched

but same problem



Transferred substrate
device